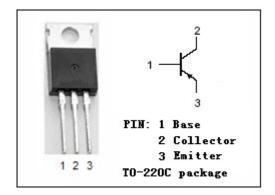




# isc Silicon PNP Power Transistor

### **DESCRIPTION**

- · Collector-Emitter Breakdown Voltage-
  - : V<sub>(BR)CEO</sub>= -60V(Min)
- · Good Linearity of hFE
- Wide Area of Safe Operation
- Complement to Type 2SD855
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

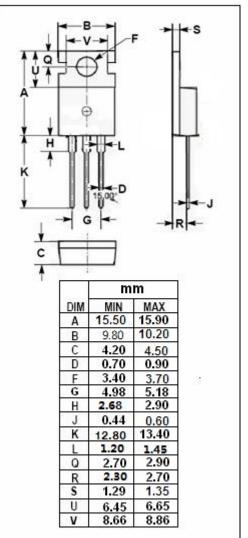


### **APPLICATIONS**

· Medium power amplifier applications.

### ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT	
V <sub>CBO</sub>	Collector-Base Voltage	-60	V	
V <sub>CEO</sub>	Collector-Emitter Voltage	-60	V	
V <sub>EBO</sub>	Emitter-Base Voltage	-5	V	
lc	Collector Current-Continuous	-1	А	
Ісм	Collector Current-Peak	-2	А	
P <sub>C</sub>	Collector Power Dissipation @ T <sub>C</sub> =25℃	30	W	
TJ	Junction Temperature	150	$^{\circ}$	
T <sub>stg</sub>	T <sub>stg</sub> Storage Temperature Range		$^{\circ}$	





## isc Silicon PNP Power Transistor

2SB760

### **ELECTRICAL CHARACTERISTICS**

 $T_c=25$ °C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> = -30mA; I <sub>B</sub> = 0	-60			٧
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	I <sub>C</sub> = -1A; I <sub>B</sub> = -0.125A			-1.0	٧
V <sub>BE(on)</sub>	Base-Emitter On Voltage	I <sub>C</sub> = -1A; V <sub>CE</sub> = -4V			-1.3	V
I <sub>CEO</sub>	Collector Cutoff Current	V <sub>CE</sub> = -60V; I <sub>B</sub> = 0			-300	μА
ІЕВО	Emitter Cutoff Current	V <sub>EB</sub> = -5V; I <sub>C</sub> = 0			-1	mA
h <sub>FE-1</sub>	DC Current Gain	I <sub>C</sub> = -0.2A; V <sub>CE</sub> = -4V	40		250	
h <sub>FE-2</sub>	DC Current Gain	I <sub>C</sub> = -1A; V <sub>CE</sub> = -4V	15			

### ♦ h<sub>FE-1</sub> Classifications

R	Q	Р
40-90	70-150	120-250

### **NOTICE:**

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